NSN 5962-01-412-8373

Memory Microcircuit - Page 1 of 1

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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Terminal Surface Treatment:

Solder

Product Name:

Programmed uve prom

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

200.00 nanoseconds delay

Memory Device Type:

Prom

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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